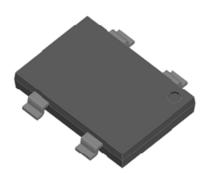
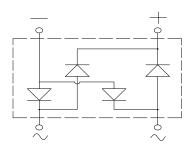




Fast Recovery Bridge Rectifiers





Features

- UL recognition, file #E313149
- Glass passivated chip junction
- Ideal for automated placement
- High surge current capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

Typical Applications

General purpose use in AC/DC bridge full wave rectification for SMPS, lighting ballaster, adapter, battery charger, home appliances, office equipment, and telecommunication applications.

Mechanical Data

• Package: YBS3

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, Halogen-free

• **Terminals**: Tin plated leads, solderable per J-STD-002 and JESD22-B102

• Polarity: As marked on body

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	RYBSM4010
Device marking code			RYBSM4010
Maximum Repetitive Peak Reverse Voltage	VRRM	V	1000
Maximum RMS Voltage	VRMS	V	700
Maximum DC blocking Voltage	VDC	V	1000
Average rectified output current @60Hz sine wave, R-load, Tc=86°C	Ю	Α	4.0
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave,1 cycle, Tj=25°C	leon		120
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25°C	IFSM	A	240
Current squared time @1ms≤t≤8.3ms Tj=25°C, Rating of per diode	I²t	A ² s	59.8
Storage temperature	T _{stg}	°C	-55 ~ +150
Junction temperature	Tj	°C	-55 ~ +150

■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	RYBSM4010
Maximum reverse recovery time	t _{rr}	ns	I _F =0.5A,I _R =1.0A, I _n =0.25A	500
Maximum instantaneous forward voltage drop per diode	VF	٧	IFM=2.0A	1.3
Maximum DC reverse current at rated DC blocking voltage	IR	μA	T _j =25℃	5
per diode	ıK.	μΑ	T _j =125°C	100
Typical junction capacitance	Cj	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C	50

RYBSM4010

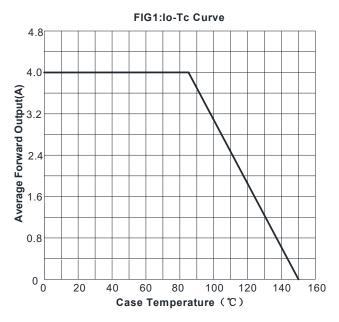
	PARAMETER	SYMBOL	UNIT	RYBSM4010
	Between Junction and Ambient	$R_{\theta J\text{-}A}$		55
Typical Thermal Resistance	Between Junction and Lead	$R_{\theta J\text{-}L}$	°C/W	14
recictarios	Between Junction and Case	R _{θJ-C}		8

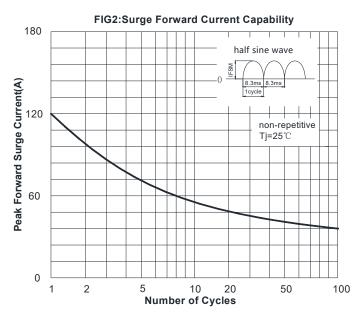
Note: Device mounted on P.C.B with 35mm*25mm*1.7mm.

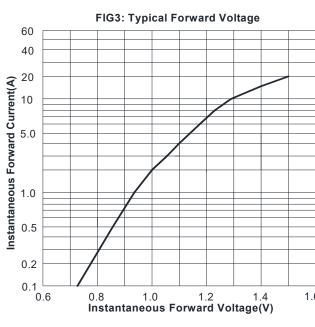
■Ordering Information (Example)

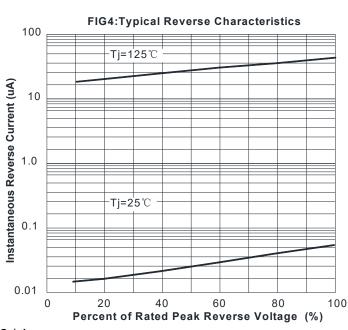
PREFERED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
RYBSM4010	F1	Approximate 0.36	1800	3600	25200	13" Reel

■ Characteristics(Typical)





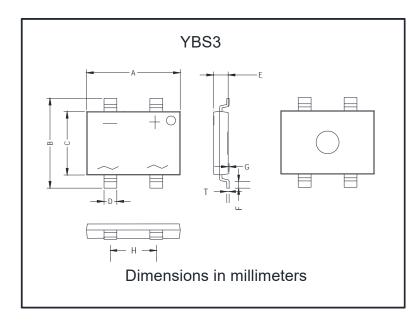




10 Ω NONINDUCTIVE $\mathbf{50}~\Omega$ trr NONINDUCTIVE +0.5A **≠** DUT 0 PULSE GENERATOR -0.25A (NOTE2) OSCILLOSCOPE ≨1Ω (NOTE1) NOTES: 1.Rise Time=7ns max .Inpot Impedance=1M Ω 22pf 2.Rise Time=10ns max.Sourse Impedance=50 Ω -1.0A SET TIME BASE FOR 5/10ns/cm

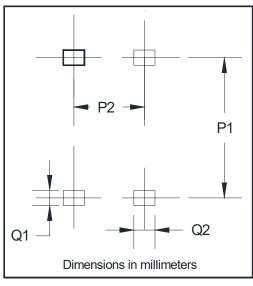
FIG.5: Diagram of circuit and Testing wave form of reverse recovery time

■ Outline Dimensions



YBS3				
Dim	Min	Max		
Α	10.00	10.40		
В	9.70	10.10		
С	6.80	7.20		
D	1.3	1.5		
E	1.4	1.8		
F	0.5	1.1		
G	0	0.15		
Н	4.9	5.1		
Т	0.20	0.30		

■ Suggested pad layout



YBS3		
Dim Min		
P1	9.25	
P2	5.00	
Q1	1.00	
Q2	1.5	

3/4



RYBSM4010

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